

Restart of Hitachi Power semiconductor production after Great East Japan Earthquake on March 11.

June 15th, 2011

We are pleased to announce that Hitachi has restarted power semiconductor production, which had been suspended after the earthquake which struck Japan on March 11th 2011.

1. Diodes

Diodes production has started since April 18th at Haramachi works.(*1) and the production volume has been already recovered to the pre-quake level.

As for the certain parts, new production line at a new factory (*2) in Yamanashi-prefecture is to be in operation simultaneously and they will aim to stabilize the availability by Nov. 2011.

2. High voltage monolithic IC

The delivery of this item has been restarted since April 4th 2011, however production volume is still yet to recover to former capacity levels. We are expecting to recover production to those levels before the earthquake around October 2011.

3. IGBT

From April 14th 2011, IGBT delivery was restarted using inventory stock after production restart.

In response to increasing demand for Hitachi IGBTs, Hitachi relocated its assembly lines from Haramachi works to a new factory located in Yamanashi-prefecture in order to strengthen production capacity. From October 2011, production capacity will be doubled versus the pre-quake capacity level.

Thank you for your continued patronage to Hitachi Power semiconductors.

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(*2) Hitachi Haramachi Electronics,Co., Ltd., Yamanashi Works: Chuo-shi ,Yamanashi-prefecture, Japan